

T-46-23-09

Description

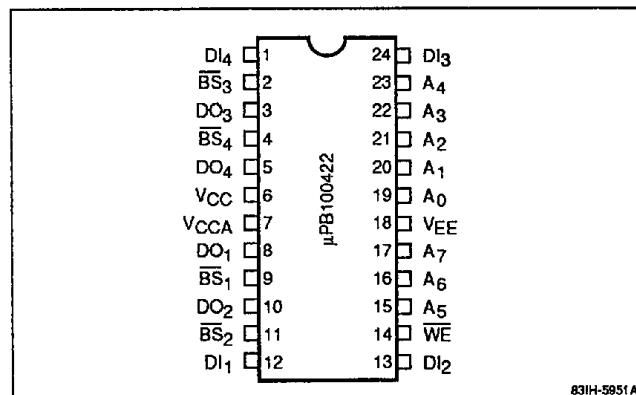
The μPB100422 is a very high-speed 100K interface ECL RAM organized as 256 words by 4 bits and designed with noninverted, open-emitter outputs and low power consumption. Two versions with fast access times of 7 or 10 ns maximum are available in 24-pin ceramic DIP or ceramic flatpack packaging.

Features

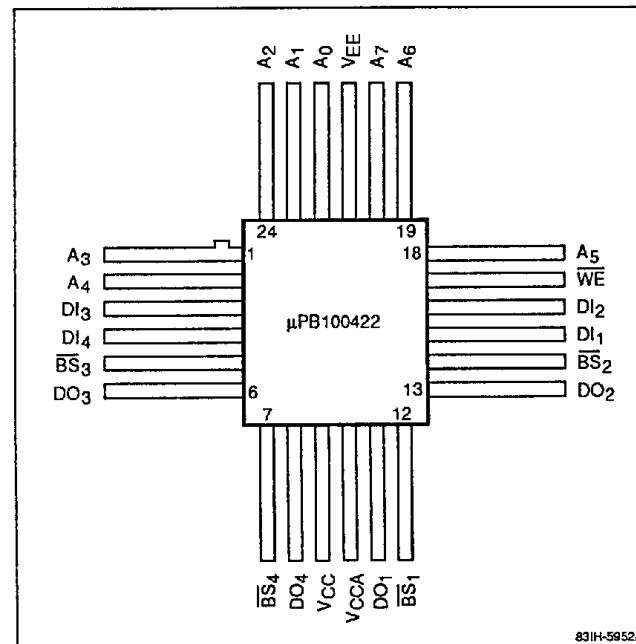
- 256-word x 4-bit organization
- 100K ECL interface
- Noninverted, open-emitter outputs
- Fast access times
- Low power consumption
- 400-mil, 24-pin ceramic DIP or 24-pin ceramic flatpack packaging

Ordering Information

Part Number	Access Time (max)	Supply Current (min)	Package
μPB100422D-7	7 ns	-220 mA	24-pin ceramic DIP
D-10	10 ns		
μPB100422B-7	7 ns	-220 mA	24-pin ceramic flatpack
B-10	10 ns		

Pin Configurations**24-Pin Ceramic DIP**

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24-Pin Ceramic Flatpack

Pin Identification

Symbol	Function
A ₀ - A ₇	Addresses
\bar{BS}_1 - \bar{BS}_4	Block select inputs
DI ₁ - DI ₄	Data inputs
DO ₁ - DO ₄	Data outputs
WE	Write enable
V _{CC}	Power supply (current switches and bias driver)
V _{CCA}	Power supply (output devices)
V _{EE}	Power supply

Capacitance

Parameter	Symbol	Min	Typ	Max	Unit
Input capacitance	C _{IN}	4		5	pF
Output capacitance	C _{OUT}	5		6	pF

Absolute Maximum Ratings

Supply voltage, V _{EE} to V _{CC}	-7.0 to +0.5 V
Input voltage, V _{IN}	V _{EE} to +0.5 V
Output current, I _{OUT}	-30 to +0.1 mA
Storage temperature, T _{STG}	-65 to +150°C
Storage temperature, under bias, T _{STG} (bias)	-55 to +125°C

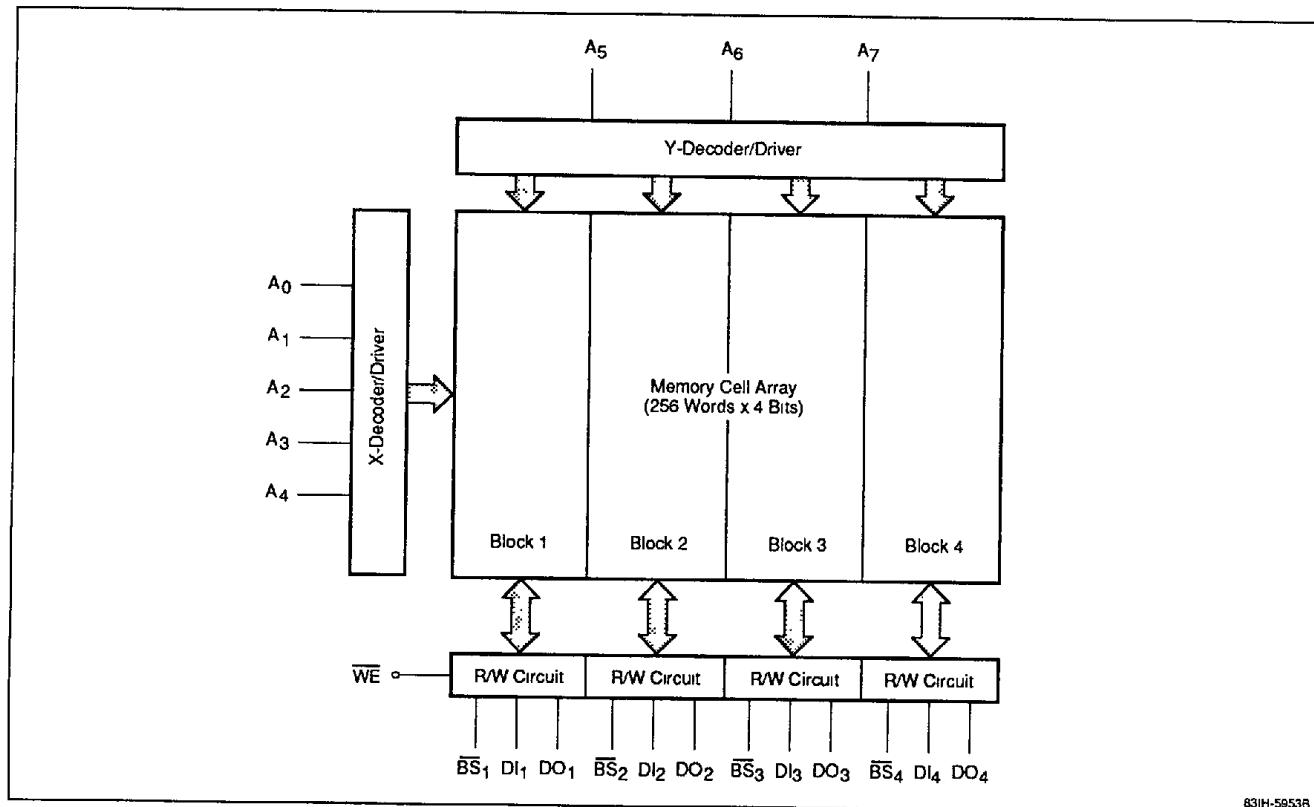
Exposure to Absolute Maximum Ratings for extended periods may affect device reliability; exceeding the ratings could cause permanent damage. The device should be operated within the limits specified under DC and AC Characteristics.

Truth Table

BS	WE	DI	DO	Function
H	X	X	L	Not Selected
L	L	L	L	Write "0"
L	L	H	L	Write "1"
L	H	X	Data Valid	Read

Notes:

- (1) The Block Select input for each of the four memory blocks is used independently as shown in the block diagram.

Block Diagram

83IH-59538

DC Characteristics $T_A = 0 \text{ to } +85^\circ\text{C}$; $V_{EE} = -4.5 \text{ V}$; output load = 50Ω to -2.0 V

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Output voltage, high	V_{OH}	-1025		-880	mV	$V_{IN} = V_{IH}$ max or V_{IL} min
Output voltage, low	V_{OL}	-1810		-1620	mV	$V_{IN} = V_{IH}$ max or V_{IL} min
Output threshold voltage, high	V_{OHC}	-1035			mV	$V_{IN} = V_{IH}$ min or V_{IL} max
Output threshold voltage, low	V_{OLC}			-1610	mV	$V_{IN} = V_{IH}$ min or V_{IL} max
Input voltage, high	V_{IH}	-1165		-880	mV	For all inputs
Input voltage, low	V_{IL}	-1810		-1475	mV	For all inputs
Input current, high	I_{IH}			220	μ A	$V_{IN} = V_{IH}$ max
Input current, low	I_{IL}	0.5		170	μ A	For BS ₁ -BS ₄ : $V_{IN} = V_{IL}$ min
		-50			μ A	For all others: $V_{IN} = V_{IL}$ min
Supply current	I_{EE}	-220			mA	All inputs and outputs open

Notes:

- (1) Device under test is mounted in a test socket and measured at a thermal equilibrium established with a transverse air flow maintained at greater than 2.0 m/s.

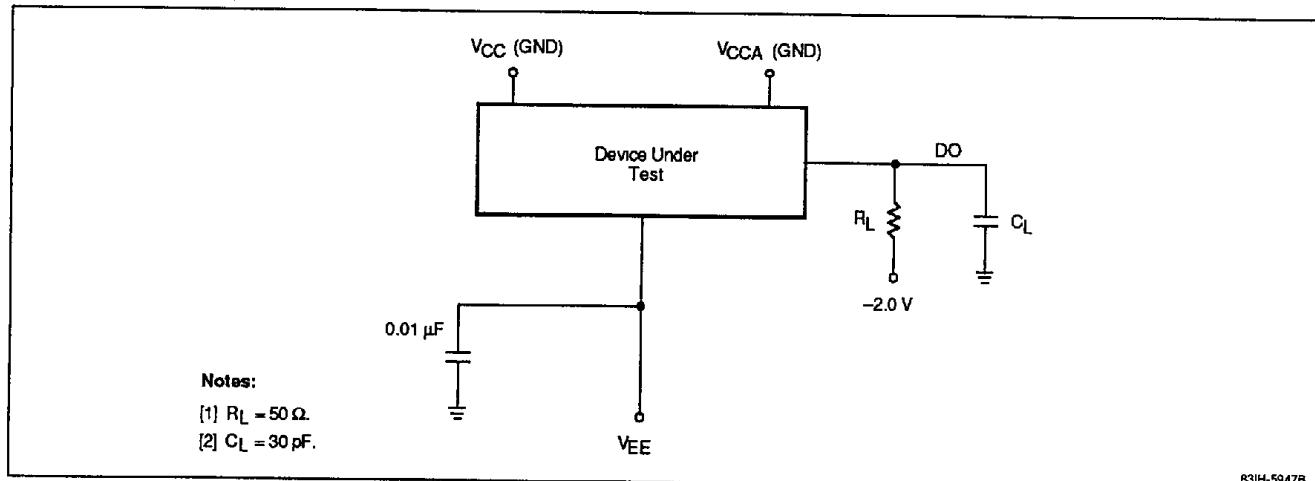
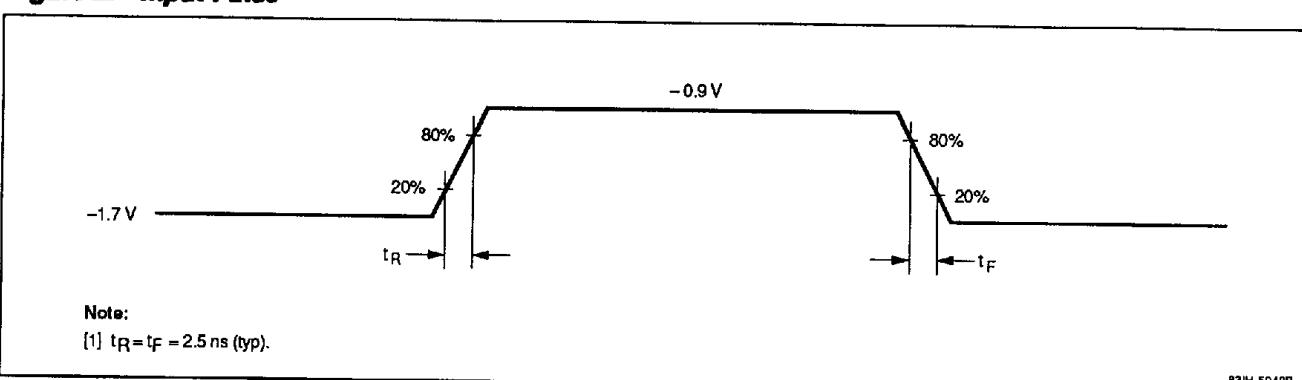
AC Characteristics $T_A = 0 \text{ to } +85^\circ\text{C}$; $V_{EE} = -4.5 \text{ V} \pm 5\%$

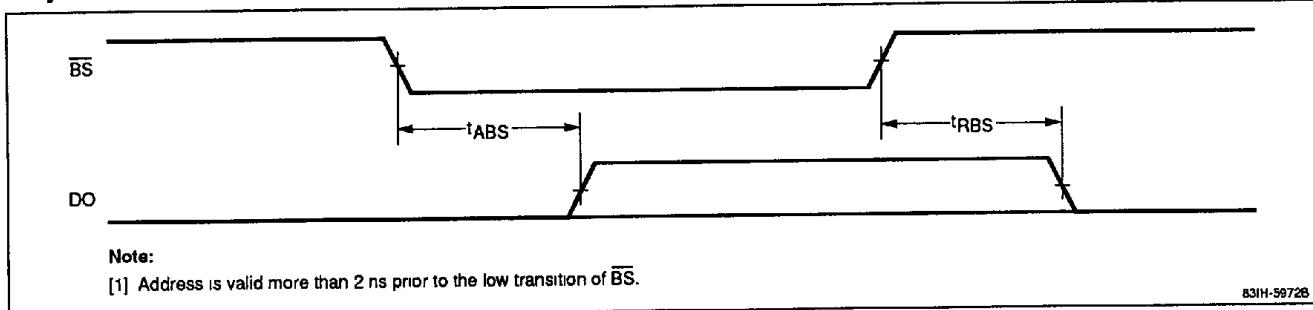
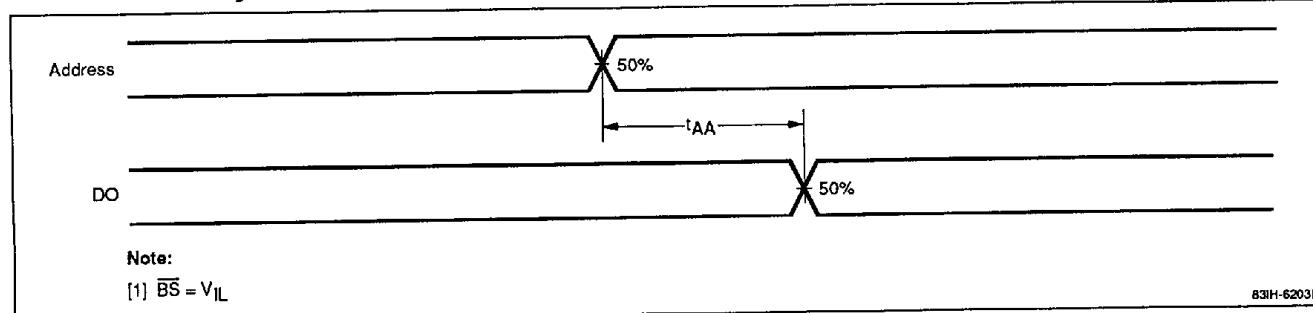
Parameter	Symbol	μ PB100422-7			μ PB100422-10			Test Conditions
		Min	Typ	Max	Min	Typ	Max	
Read Operation								
Block select access time	t_{ABS}			5			5	ns
Block select recovery time	t_{RBS}			5			5	ns
Address access time	t_{AA}			7			10	ns
Write Operation								
Write pulse width	t_W	5		6				ns
Data setup time	t_{WSD}	1		2				ns
Data hold time	t_{WHD}	1		2				ns
Address setup time	t_{WSA}	1		2				ns
Address hold time	t_{WHA}	1		2				ns
Block select setup time	t_{WSBS}	1		2				ns
Block select hold time	t_{WHBS}	1		2				ns
Write disable time	t_{WS}			5			5	ns
Write recovery time	t_{WR}			6			9	ns
Output Rise and Fall Times								
Output rise time	t_R		2			2		ns
Output fall time	t_F		2			2		ns

Notes:

- (1) Device under test is mounted in a test socket and measured at a thermal equilibrium established with a transverse air flow maintained at greater than 2.0 m/s.
- (2) All timing measurements are referenced to 50% input levels.
- (3) The output load is shown in figure 1.
- (4) Input transition times are shown in figure 2.

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Figure 1. Loading Conditions Test Circuit**Figure 2. Input Pulse**

Timing Waveforms**Chip Select Access****26a****Address Access Cycle****Write Cycle**